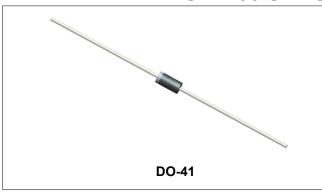






SB1100 SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters,
 Free Wheeling, and Polarity Protection Applications
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- · Switching power supply
- Converters
- Free-Wheeling diodes
- · Reverse battery protection
- Disk drives
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	1	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _C =25°C	40	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 1A, Pulse, T _J = 25 °C		0.85	V
	V _{F2}	@ 1A, Pulse, T _J = 125 °C	0.65	0.75	V
Reverse Current*	I _{R1}	@V _R = Rated V _R , Pulse, T _J = 25 °C	0.0003	1.0	mA
	I _{R2}	$@V_R = Rated V_R, Pulse, T_J = 125 °C$	0.2	15	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	40	80	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/us

^{*} Pulse width < 300 µs, duty cycle < 2%







Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	50	°C/W
Approximate Weight	wt	-	0.26	g

Ratings and Characteristics Curves

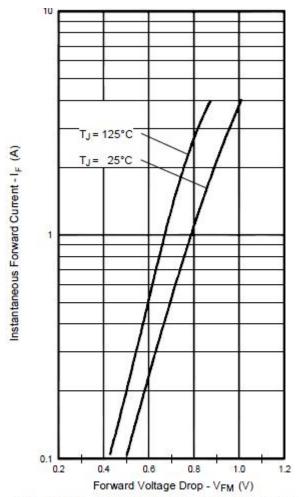


Fig. 1 Max. Forward Voltage Drop Characteristics (Per Leg)

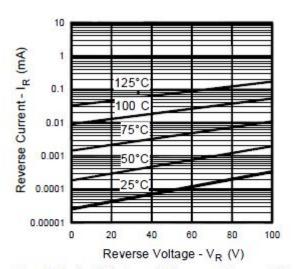


Fig. 2 Typical Values of Reverse Current Vs. Reverse Voltage (Per Leg)

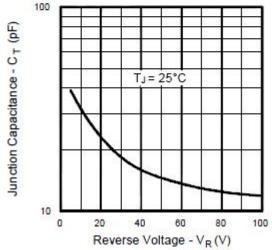


Fig. 3 Typical Junction CapacitanceVs. Reverse Voltage (Per Leg)

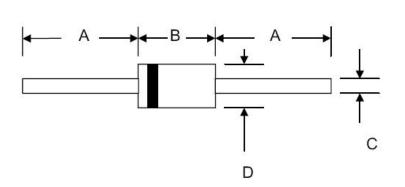
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Mechanical Dimensions DO-41



CVMPOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	4.06	5.21	0.160	0.205	
С	0.71	0.864	0.028	0.034	
D	2.00	2.72	0.079	0.107	

Ordering Information

Device	Package	Shipping
SB1100	DO-41(Pb-Free)	5000pcs / tape
SB1100TA	DO-41(Pb-Free)	5000pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

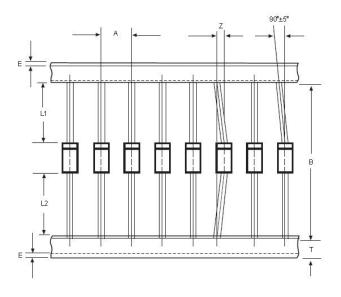
Marking Diagram



SB1100

= Part Name

Carrier Tape Specification DO-41



SYMBOL	Millimeters			
STWIBOL	Min.	Max.		
А	4.50	5.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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